

Product data sheet

1. Product profile

1.1 General description

Planar passivated four quadrant triac in a SOT78 (TO-220AB) plastic package intended for use in general purpose bidirectional switching and phase control applications, where high sensitivity is required in all four quadrants. This very sensitive gate "series D" triac is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

1.2 Features and benefits

- Direct triggering from low power drivers and logic ICs
- High blocking voltage capability
- Low holding current for low current loads and lowest EMI at commutation

1.3 Applications

General purpose motor control

- Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants
- Very sensitive gate for easy logic level triggering
- General purpose switching

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	600	V
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 20 \text{ ms}$; see <u>Figure 4</u> ; see <u>Figure 5</u>	-	-	35	A
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 110 °C; see <u>Figure 1</u> ; see <u>Figure 2</u> ; see <u>Figure 3</u>	-	-	4	A



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Table 1.	Quick referen	ice data	continued
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Parameter	Conditions	Min	Тур	Max	Unit
aracteristics					
gate trigger current	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T}2+ \text{ G}+;$ $T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure 7}}{2}$	-	-	5	mA
	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2+ G-};$ $T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure 7}}{7}$	-	-	5	mA
	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2- G-};$ $T_j = 25 ^\circ\text{C}; \text{ see } \frac{\text{Figure 7}}{7}$	-	-	5	mA
	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2- G+};$ $T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure 7}}{2}$	-	-	10	mA
	Parameter aracteristics	$\begin{array}{c c} \mbox{Parameter} & \mbox{Conditions} \\ \hline \mbox{aracteristics} \\ \hline \mbox{gate trigger current} & V_D = 12 \ V; \ I_T = 0.1 \ A; \ T2+ \ G+; \\ T_j = 25 \ ^\circ\ C; \ see \ \underline{Figure \ 7} \\ \hline V_D = 12 \ V; \ I_T = 0.1 \ A; \ T2+ \ G-; \\ T_j = 25 \ ^\circ\ C; \ see \ \underline{Figure \ 7} \\ \hline V_D = 12 \ V; \ I_T = 0.1 \ A; \ T2- \ G-; \\ T_j = 25 \ ^\circ\ C; \ see \ \underline{Figure \ 7} \\ \hline V_D = 12 \ V; \ I_T = 0.1 \ A; \ T2- \ G-; \\ T_j = 25 \ ^\circ\ C; \ see \ \underline{Figure \ 7} \\ \hline V_D = 12 \ V; \ I_T = 0.1 \ A; \ T2- \ G+; \\ \hline \ T_j = 25 \ ^\circ\ C; \ see \ \underline{Figure \ 7} \\ \hline \ V_D = 12 \ V; \ I_T = 0.1 \ A; \ T2- \ G+; \\ \hline \ T_j = 25 \ ^\circ\ C; \ see \ \underline{Figure \ 7} \\ \hline \ V_D = 12 \ V; \ I_T = 0.1 \ A; \ T2- \ G+; \\ \hline \ T_j = 25 \ ^\circ\ C; \ see \ \underline{Figure \ 7} \\ \hline \ T_j = 25 \ ^\circ\ C; \ see \ \underline{Figure \ 7} \\ \hline \ T_j = 25 \ ^\circ\ C; \ see \ \underline{Figure \ 7} \\ \hline \ T_j = 25 \ ^\circ\ C; \ see \ \underline{Figure \ 7} \\ \hline \ T_j = 12 \ V; \ I_T = 0.1 \ A; \ T2- \ G+; \\ \hline \ T_j = 12 \ V; \ I_T = 0.1 \ A; \ T2- \ G+; \\ \hline \ T_j = 12 \ V; \ I_T = 0.1 \ A; \ T2- \ G+; \\ \hline \ T_j = 12 \ V; \ T_j = 0.1 \ A; \ T2- \ G+; \\ \hline \ T_j = 12 \ V; \ T_j = 0.1 \ A; \ T2- \ G+; \\ \hline \ T_j = 12 \ V; \ T_j = 0.1 \ A; \ T2- \ G+; \\ \hline \ T_j = 12 \ V; \ T_j = 0.1 \ A; \ T2- \ G+; \\ \hline \ T_j = 12 \ V; \ T_j = 0.1 \ A; \ T2- \ G+; \\ \hline \ T_j = 12 \ V; \ T_j = 0.1 \ A; \ T2- \$	$\begin{array}{ c c c c c } \hline Parameter & Conditions & Min \\ \hline aracteristics \\ \hline gate trigger current & V_D = 12 \ V; \ I_T = 0.1 \ A; \ T2+ \ G+; & - \\ T_j = 25 \ ^\circ \ C; \ see \ \underline{Figure \ 7} & \\ \hline V_D = 12 \ V; \ I_T = 0.1 \ A; \ T2+ \ G-; & - \\ T_j = 25 \ ^\circ \ C; \ see \ \underline{Figure \ 7} & \\ \hline V_D = 12 \ V; \ I_T = 0.1 \ A; \ T2- \ G-; & - \\ T_j = 25 \ ^\circ \ C; \ see \ \underline{Figure \ 7} & \\ \hline V_D = 12 \ V; \ I_T = 0.1 \ A; \ T2- \ G-; & - \\ T_j = 25 \ ^\circ \ C; \ see \ \underline{Figure \ 7} & \\ \hline V_D = 12 \ V; \ I_T = 0.1 \ A; \ T2- \ G-; & - \\ \hline T_j = 25 \ ^\circ \ C; \ see \ \underline{Figure \ 7} & \\ \hline V_D = 12 \ V; \ I_T = 0.1 \ A; \ T2- \ G+; & - \\ \hline \end{array}$	$\begin{array}{c c} \mbox{Parameter} & \mbox{Conditions} & \mbox{Min} & \mbox{Typ} \\ \hline \mbox{aracteristics} \\ \hline \mbox{gate trigger current} & \begin{tabular}{ll} V_D = 12 \ V; \ I_T = 0.1 \ A; \ T2+ \ G+; & - & - \\ \hline \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

2. Pinning information

Table 2.	Pinning	j information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1		N. 1
2	T2	main terminal 2	mb	T2-T1
3	G	gate		Sym051
mb	Τ2	mounting base; main terminal 2		

1 2 3 SOT78 (TO-220AB)

3. Ordering information

Table 3.Ordering information

Type number	Package		
	Name	Description	Version
BT234-600D	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78

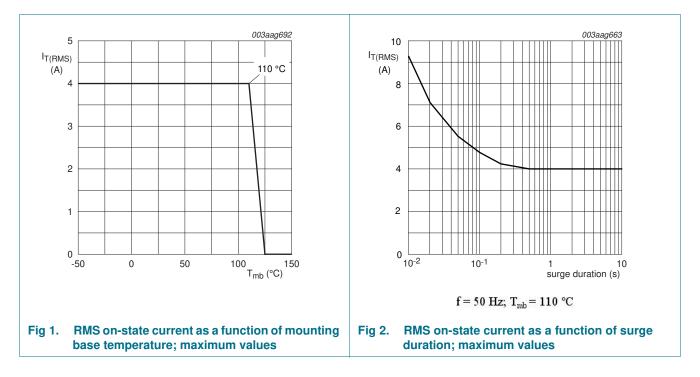
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4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

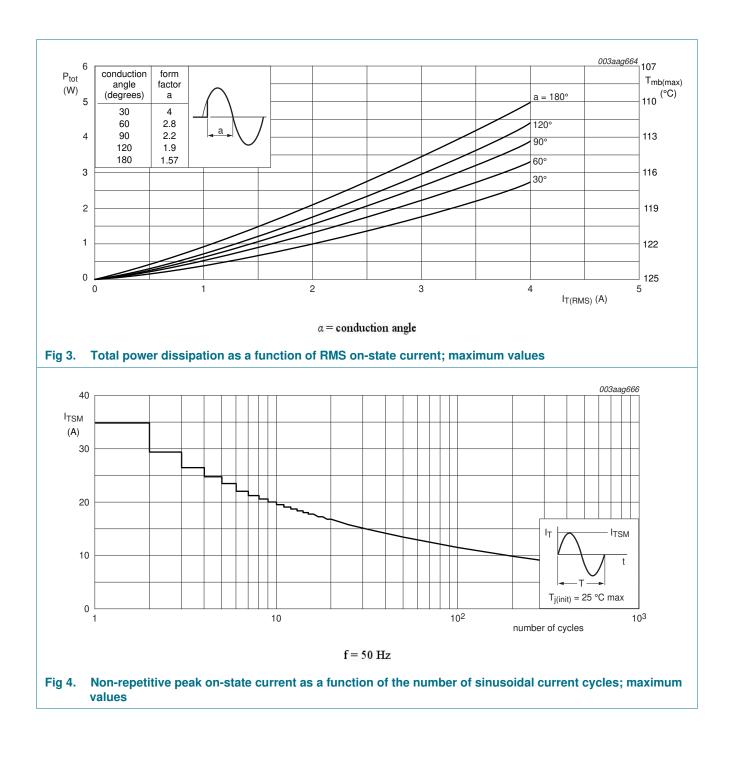
Symbol	Parameter	Conditions	Min	Мах	Unit
V _{DRM}	repetitive peak off-state voltage		-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 110 °C; see <u>Figure 1</u> ; see <u>Figure 2</u> ; see <u>Figure 3</u>	-	4	А
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 20 \text{ ms}$; see <u>Figure 4</u> ; see <u>Figure 5</u>	-	35	А
		full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 16.7 \text{ ms}$	-	38.5	Α
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	6.1	A ² s
dI _T /dt	rate of rise of on-state current	I_T = 7 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2+ G+	-	50	A/µs
		I_T = 7 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2+ G-	-	50	A/µs
		I_T = 7 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2- G-	-	50	A/µs
		I_T = 7 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2- G+	-	10	A/µs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
T _i	junction temperature		-	125	°C



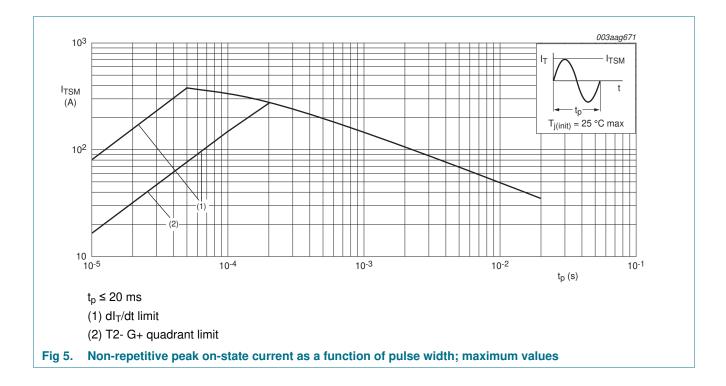
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5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting	half cycle; see Figure 6	-	-	3.7	K/W
	base	full cycle; see Figure 6	-	-	3	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	60	-	K/W

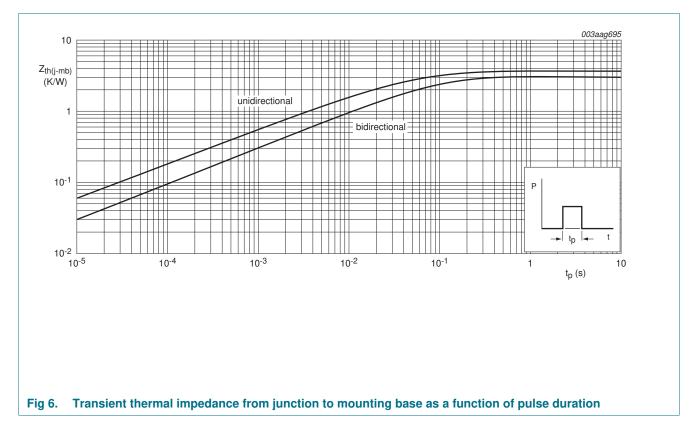


Table 5. Thermal characteristics

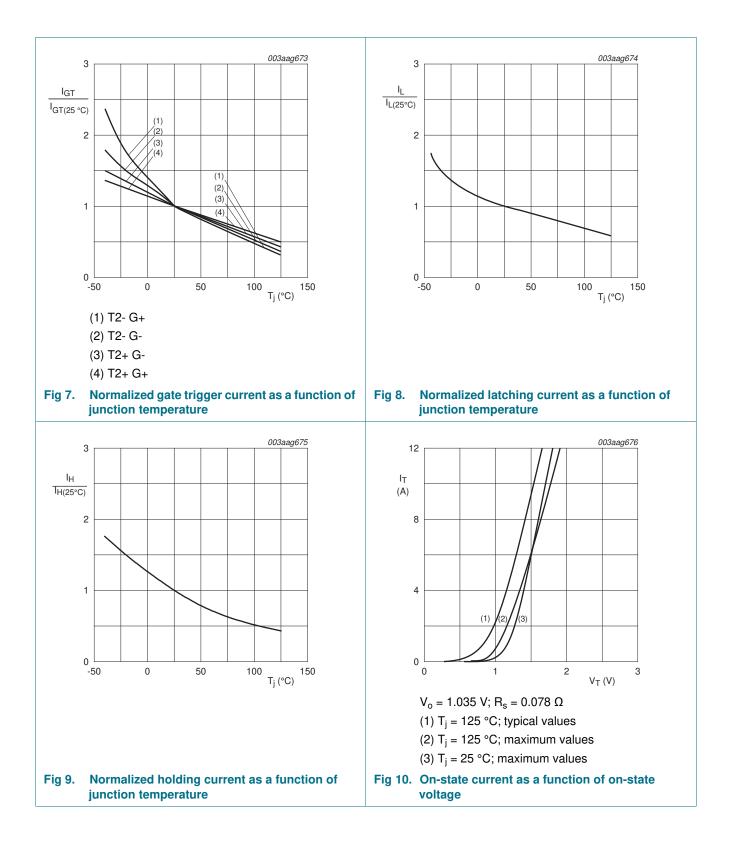
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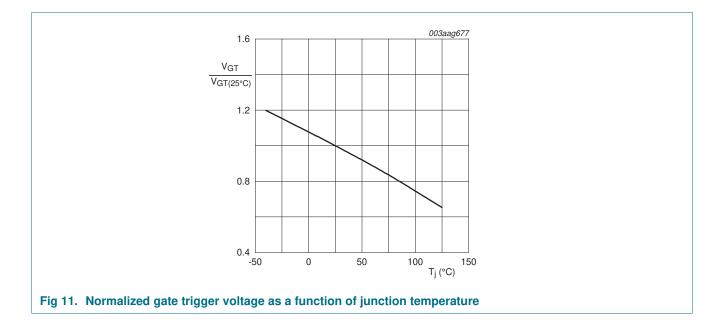
6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{T2+ G+}; \text{T}_j = 25 \text{ °C};$ see <u>Figure 7</u>	-	-	5	mA
		$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2+ G-}; \text{T}_j = 25 \text{ °C};$ see <u>Figure 7</u>	-	-	5	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2- G-}; \text{ T}_j = 25 \text{ °C};$ see Figure 7	-	-	5	mA
		$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2- G+}; \text{T}_j = 25 \text{ °C};$ see <u>Figure 7</u>	-	-	10	mA
IL	latching current	$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G+}; \text{ T}_j = 25 \text{ °C};$ see Figure 8	-	-	10	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G-}; \text{ T}_j = 25 \text{ °C};$ see Figure 8	-	-	15	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-}; \text{ T}_j = 25 \text{ °C};$ see Figure 8	-	-	10	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G+}; \text{ T}_j = 25 \text{ °C};$ see Figure 8	-	-	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; see <u>Figure 9</u>	-	-	6	mA
V _T	on-state voltage	$I_T = 6 \text{ A}; T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure } 10}{10}$	-	1.3	1.5	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; see <u>Figure 11</u>	-	0.7	1.5	V
		$V_D = 400 \text{ V}; I_T = 0.1 \text{ A}; T_j = 125 \text{ °C};$ see <u>Figure 11</u>	0.25	0.4	-	V
I _D	off-state current	$V_D = 600 \text{ V}; \text{ T}_j = 125 \text{ °C}$	-	0.1	0.5	mA
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 125 °C; exponential waveform; gate open circuit	-	50	-	V/µs
dl _{com} /dt	rate of change of commutating current	$ V_D = 400 \; V; \; T_j = 125 \; ^\circ C; \; I_{T(RMS)} = 4 \; A; \\ dV_{com}/dt = 20 \; V/\mu s; \; (snubberless condition); \\ gate \; open \; circuit $	-	1.2	-	A/ms
t _{gt}	gate-controlled turn-on time	I_{TM} = 6 A; V_D = 600 V; I_G = 0.1 A; dI_G/dt = 5 A/µs	-	2	-	μs

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Package outline 7.

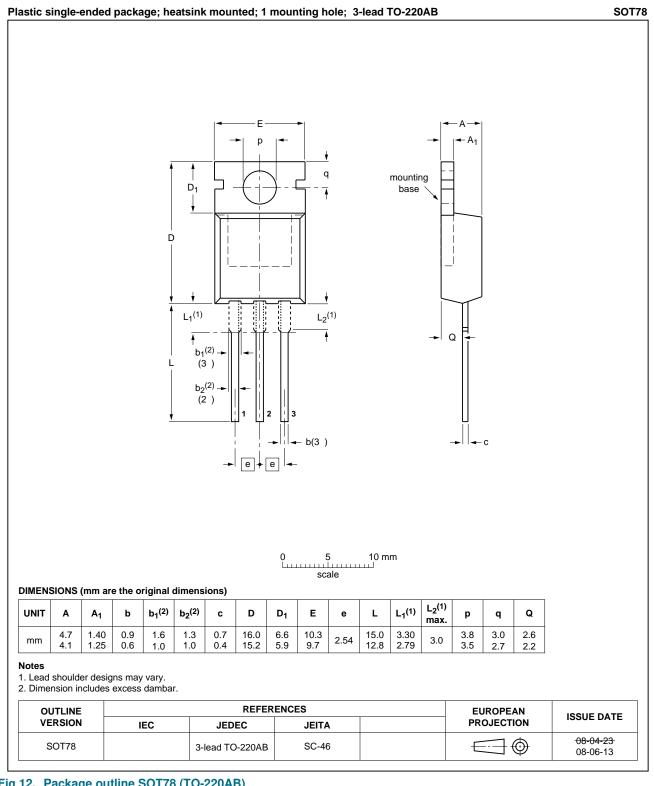


Fig 12. Package outline SOT78 (TO-220AB)

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8. Revision history

Table 7. Re	Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes	
BT234-600D v	1 20111004	Product data sheet	-	-	

9. Legal information

9.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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